TOSHIBA Field-Effect Transistor Silicon N Channel MOS Type

SSM6N40TU

- O Power Management Switch Applications
- O High-Speed Switching Applications
- 4 V drive
- N-ch 2-in-1

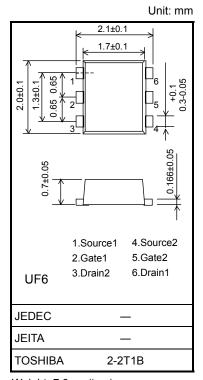
• Low ON-resistance: $R_{on} = 182m\Omega \text{ (max) } (@V_{GS} = 4 \text{ V})$

 $R_{on} = 122m\Omega \text{ (max) (@V_{GS} = 10 V)}$

Absolute Maximum Ratings (Ta = 25 °C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	30	V	
Gate-source voltage		V _{GSS}	± 20	V	
Drain current	DC	ID	1.6	Α	
	Pulse	I _{DP}	3.2		
Drain power dissipation		P _D (Note1)	500	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 7.0mg (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Mounted on an FR4 board. (total dissipation) $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu Pad}: 645 \text{ mm}^2)$

Electrical Characteristics (Ta = 25°C) (Q1,Q2 Common)

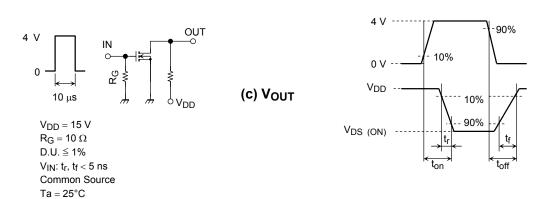
Char	acteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	$I_D = 1$ mA, $V_{GS} = 0$ V	30	_		V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -20 \text{ V}$	15	_	_	V
Drain cutoff currer	nt	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	1	μА
Gate leakage curr	ent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Gate threshold vo	tage	V_{th}	$V_{DS} = 5 \text{ V}, I_D = 1 \text{ mA}$	1.0	_	2.6	V
Forward transfer a	idmittance	Y _{fs}	$V_{DS} = 5 \text{ V}, I_D = 1A$ (Note 2)	1.9	3.7	_	S
Drain-source ON-resistance		R _{DS (ON)}	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V}$ (Note 2)	_	96	122	mΩ
			$I_D = 0.5 \text{ A}, V_{GS} = 4 \text{ V}$ (Note 2)	_	130	182	
Input capacitance		C _{iss}		_	180		
Output capacitance Reverse transfer capacitance		Coss	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	34		pF
		C _{rss}		_	27	_	
Total Gate Charge Gate–Source Charge Gate–Drain Charge		Q_g	V 45 V 1 4 0 A	_	5.1		nC
		Q_{gs}	$V_{DS} = 15 \text{ V}, I_{D} = 1.6 \text{ A}$	_	3.9	_	
		Q_{gd}	V _{GS} = 10 V	_	1.2		
Switching time	Turn-on time	ton	V _{DD} = 15 V, I _D = 0.5 A	_	9.5	_	ns
	Turn-off time	t _{off}	$V_{GS} = 0~4~V,~R_{G} = 10~\Omega$	_	9.0	_	
Drain-source forward voltage		V _{DSF}	$I_D = -1.6 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 2)	_	-0.8	-1.2	V

Note 2: Pulse test

Switching Time Test Circuit

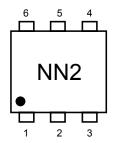


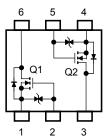




Marking

Equivalent Circuit (top view)





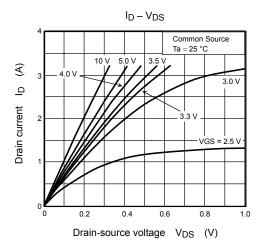
Notice on Usage

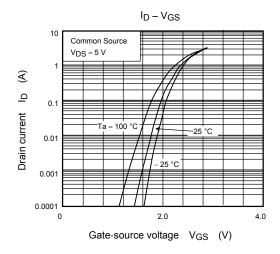
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is I_D = 1 mA for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} and V_{GS} (off) requires a lower voltage than V_{th} . (The relationship can be established as follows: V_{GS} (off) < V_{th} < V_{GS} (on).)

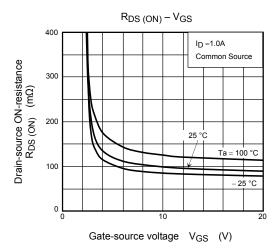
Take this into consideration when using the device.

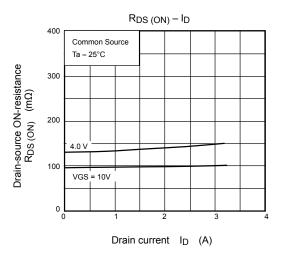
Handling Precaution

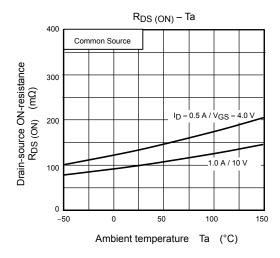
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

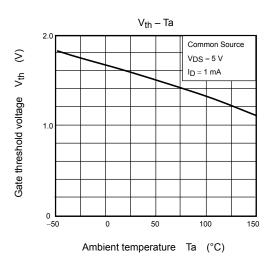


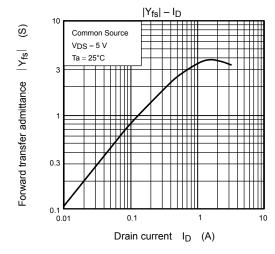


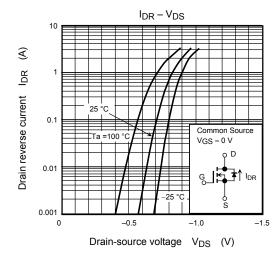


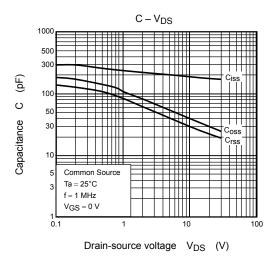


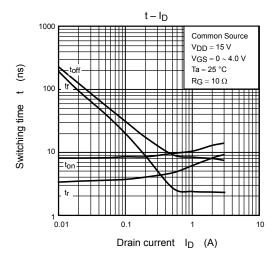


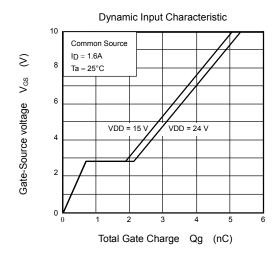


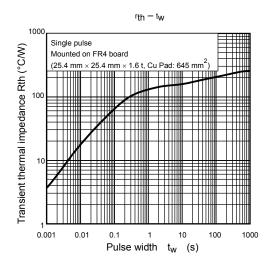


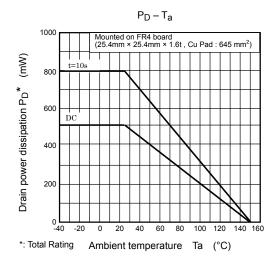












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